

40V NPN SILICON PLANAR MEDIUM POWER TRANSISTOR IN SOT89

Features

- BV_{CEO} > 40V
- I_C = 1A high Continuous Current
- Low saturation voltage V_{CE(sat)} < 500mV @ 1A
- Complementary PNP type: FCX591A
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

Mechanical Data

- Case: SOT89
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.05 grams (Approximate)

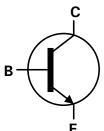
Applications

- Power MOSFET gate driving
- Low loss power switching

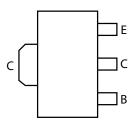
SOT89



Top View



Device Symbol



Top View Pin Out

Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FCX491ATA	AEC-Q101	N2	7	12	1,000
FCX491AQTA	Automotive	N2	7	12	1,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
- 5. For packaging details, go to our website at http://www.diodes.com.

Marking Information



N2 = Product Type Marking Code





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	40	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	1	Α
Peak Pulse Current	I _{CM}	2	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P_{D}	1	W
Thermal Resistance, Junction to Ambient Air (Note 6)	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction to Leads (Note 7)	$R_{\theta JL}$	10.01	°C/W
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-65 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Notes:

^{6.} For a device surface mounted on 15mm X 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; device measured when operating in steady state condition.

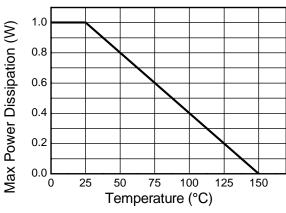
7. Thermal resistance from junction to solder-point (on the exposed collector pad).

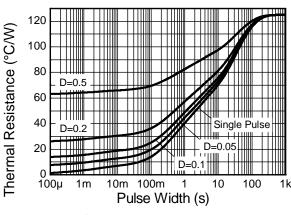
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





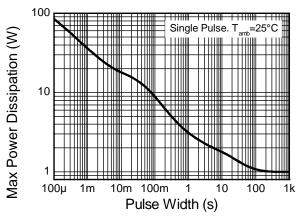
Thermal Characteristics and Derating Information





Derating Curve

Transient Thermal Impedance



Pulse Power Dissipation





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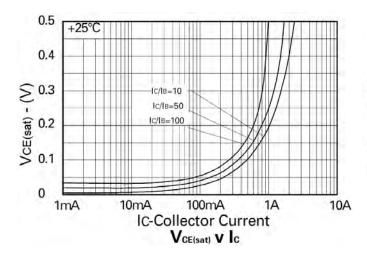
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

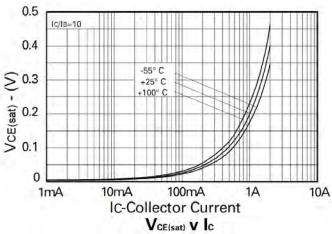
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	40	-	-	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	40	-	-	V	$I_C = 10mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	7	-	-	V	I _E = 100μA
Collector Cutoff Current	I _{CBO}	-	-	100	nA	V _{CB} = 30V
Emitter Cutoff Current	I _{EBO}	-	-	100	nA	V _{EB} = 4V
Emitter Cutoff Current	I _{CES}	-	-	100	nA	V _{CE} = 30V
DC current transfer Static ratio (Note 9)	h _{FE}	300 300 200 35	- - -	- 900 - -	-	$I_{C} = 1 \text{mA}, V_{CE} = 5 \text{V}$ $I_{C} = 500 \text{mA}, V_{CE} = 5 \text{V}$ $I_{C} = 1 \text{A}, V_{CE} = 5 \text{V}$ $I_{C} = 2 \text{A}, V_{CE} = 5 \text{V}$
Collector-Emitter Saturation Voltage (Note 9)	$V_{\text{CE(sat)}}$	-	-	0.3 0.5	V	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$ $I_C = 1A, I_B = 100 \text{mA}$
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	-	-	1.1	V	$I_C = 1A$, $I_B = 100mA$
Base-Emitter Turn-on Voltage (Note 9)	V _{BE(on)}	-	-	1.0	V	$I_C = 1A, V_{CE} = 5V$
Transitional Frequency	f _T	150	-	-	MHz	$I_{C} = 50 \text{mA}, V_{CE} = 10 \text{V}$ f = 100MHz
Output capacitance	C_{obo}	-	-	10	pF	$V_{CB} = 10V$, $f = 1MHz$,

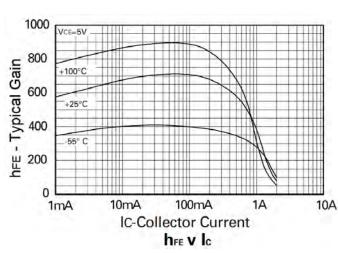
Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

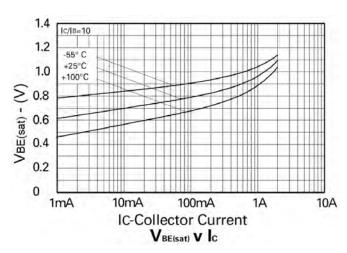


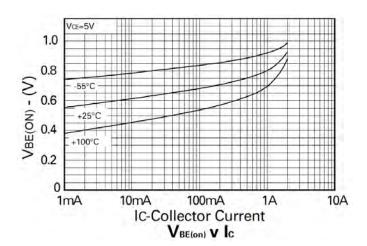
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)









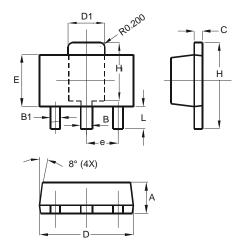






Package Outline Dimensions

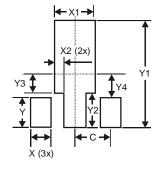
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.44		
D	4.40	4.60		
D1	1.62	1.83		
Е	2.29	2.60		
е	1.50 Typ			
Ι	3.94	4.25		
H1	2.63	2.93		
٦	0.89	1.20		
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Х	0.900		
X1	1.733		
X2	0.416		
Υ	1.300		
Y1	4.600		
Y2	1.475		
Y3	0.950		
Y4	1.125		
С	1.500		





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